Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S55	2	"20010032589".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:09
S57	336	dehydrogen$6 near15 (heat$4 or anneal$4) same (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:10
S56	470	dehydrogen$6 near15 (heat$4 or anneal$4) and (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:10
S58	4	without near5 dehydrogen$6 near15 (heat$4 or anneal$4) same (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:13
S59	51	laser near10 dehydrogen$6 near15 (heat$4 or anneal$4) same (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:17
S60	16	without near4 dehydrogen$6 same (si or silicon) near2 film	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:21
S61	165	without near4 hydrogen near15 (si or silicon) near2 (layer film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:22
S62	12	without near4 hydrogen near15 (si or silicon) near2 (layer film) same laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:26
S63	6	("5453858" "5559042" "5567967").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:32
S65	3	"5424230".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:47

S64	35	hydrogen near3 ("no") near10 (si or silicon) near10 (film or layer) and laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:47
S66	55	("5424230").URPN.	USPAT	OR	ON	2005/05/17 15:53
S67	34	("5424230").URPN. and (si or silicon) near5 hydrogen	USPAT	OR	ON	2005/05/17 16:11
S71	3	"03248574"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/17 16:12
S70	0	"30248574"	USPAT	OR	ON	2005/05/17 16:12
S69	9	"3248574"	USPAT	OR	ON	2005/05/17 16:12
S68	1	"03248574"	USPAT	OR	ON	2005/05/17 16:12
S72	2	(SAKAI near2 KATSUJI).in. and (silicon or si) near10 (hydrogen)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/17 16:13
S73	2389	optical near5 (chemical near2 vapor near2 deposit$6 or cvd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:07
S74	245	(argon near2 fluoride ArF) near2 laser near16 ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:08
S75	201	(argon near2 fluoride ArF) near2 laser near10 ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:13
S76	1467	(ion or plasma) near15 amorphous near10 (si or silicon) near15 hydrogen$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:14
S77	22	(ion or plasma) near15 amorphous near10 (si or silicon) near15 hydrogen$5 near5 ("no")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:16

S79	2	"20010032589".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:21
S78	49	(ion or plasma) near15 amorphous near10 (si or silicon) near15 dehydrogen$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 14:32
S80	2	"5795385".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:39
S82	172	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2") and @py<"1998"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:40
S81	482	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:40
S83	49	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2") near10 silane and @py<"1998"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:41
S84	1	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2") near10 silane near10 carrier and @py<"1998"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:44
S85	4	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2") near10 carrier	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:47
S87	75	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2") near4 gas and @py<"1998"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:48
S86	255	plasma near10 (cvd or chemical near2 vapor near2 deposit$6) near10 (si or silicon) near10 amorphous near10 (hydrogen or "h.sub.2") near4 gas	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/27 15:48